



Molecular Crystals and Liquid Crystals

Publication details, including instructions for authors and
subscription information:

<http://www.tandfonline.com/loi/gmcl18>

Interfacial Electron Transfer from CdS Clusters to Metalloporphyrins

J. Chrysochoos^a

^a Department of Chemistry, The University of Toledo, Toledo, 43606
Version of record first published: 04 Oct 2006.

To cite this article: J. Chrysochoos (1991): Interfacial Electron Transfer from CdS Clusters to Metalloporphyrins, *Molecular Crystals and Liquid Crystals*, 194:1, 247-252

To link to this article: <http://dx.doi.org/10.1080/00268949108041171>

PLEASE SCROLL DOWN FOR ARTICLE

Full terms and conditions of use: <http://www.tandfonline.com/page/terms-and-conditions>

This article may be used for research, teaching, and private study purposes. Any substantial or systematic reproduction, redistribution, reselling, loan, sub-licensing, systematic supply, or distribution in any form to anyone is expressly forbidden.

The publisher does not give any warranty express or implied or make any representation that the contents will be complete or accurate or up to date. The accuracy of any instructions, formulae, and drug doses should be independently verified with primary sources. The publisher shall not be liable for any loss, actions, claims, proceedings, demand, or costs or damages whatsoever or howsoever caused arising directly or indirectly in connection with or arising out of the use of this material.

INTERFACIAL ELECTRON TRANSFER FROM CdS CLUSTERS TO METALLOPORPHYRINS

J. CHRYSOCHOOS

Department of Chemistry, The University of Toledo,
Toledo, OH 43606

Abstract The efficiency of interfacial electron transfer from CdS clusters to ZnTPP and CdTPP in CH₃CN and 2-propanol increases with decreasing cluster size and in the presence of O₂. The excited singlet states of ZnTPP and CdTPP do not participate in the transfer process. Photoproducts of ZnTPP, formed in the presence of excited CdS, were monitored via their absorption and emission spectra. Interfacial electron transfer from CdS (e⁻/h⁺) was probed via the recombination luminescence of the cluster.

Keywords: Semiconductor clusters, CdS clusters, interfacial electron transfer, ZnTPP, metalloporphyrins

INTRODUCTION

Semiconductor clusters with diameters smaller than a critical one (D_{crit}), dependent upon the nature of the semiconductor under consideration, exhibit size-dependent optical and spectroscopic properties¹⁻⁵. The photogenerated charge carriers (e⁻/h⁺ pairs) experience a "space confinement" in such clusters bringing about an increase in the energy of the lowest eigenstate of the e⁻/h⁺ pair and the effective band gap of the cluster. Size-dependent determinations of the band gap energy are in fair agreement with predictions from elementary theory^{1,6-8}. Furthermore, interfacial electron transfer depends upon the nature of defects and surface states as well as the size of the cluster⁹⁻¹². The primary products of interfacial electron transfer are the acceptor radical ion (R⁻) and a positively charged cluster (radical ion). In the absence of back electron transfer the electron acceptor can be reduced to fairly stable products.

Negative ions of porphyrins and metalloporphyrins were obtained chemically in reactions of ZnTPP with sodium benzophenone ketyl in tetrahydrofuran leading to a sodium salt of [ZnTPP⁻]¹³. The Soret band of [ZnTPP⁻]⁻Na⁺ was shifted to

455 nm compared with 422 nm of ZnTPP. The dinegative anion, $[\text{ZnTPP}]^{2-} \cdot \text{Na}_2^+$, whose protonated form changes to tetraphenylphlorin with excess of methanol, was obtained with anthracene negative ions. These early observations were followed by electrochemical studies which led to the determination of the reduction potentials of ZnTPP, i.e. -1.32 and -1.73 V vs SCE in DMF¹⁴, studies of formation of porphyrin radical ions by cyclic voltametry¹⁵, formation of radical ions of metalloporphyrins¹⁶ and many other studies. Electron transfer photo-reactions in pophryins and metalloporphyrins were reviewed as early as in 1978^{16,17}. Chemical photooxidation, on the other hand, of ZnTPP was achieved more recently in CH_2Cl_2 with $\text{Fe}(\text{ClO}_4)_3$ leading to the formation of appropriate radical ions, $\text{ZnTPP}^+ \cdot \text{ClO}_4^- (\lambda_{\text{max}}=409 \text{ nm})$ and $\text{ZnTPP}^{2+} \cdot 2\text{ClO}_4^- (\lambda_{\text{max}} \approx 350 \text{ nm})$ ¹⁸. Radical cations of ZnTPP were also formed in flash photolysis studies of ZnTPP in the presence of BQH_2 and other electron acceptors with redox potential more negative than those of the excited singlet and triplet ZnTPP¹⁹.

We have been studying interfacial electron transfer from CdS clusters to inorganic redox couples (Eu^{3+} , Yb^{3+} , Sm^{3+} , etc.). The low stability of the divalent ions formed makes it difficult to monitor the yield of electron transfer. In this brief paper we present preliminary results of light induced electron-transfer between excited CdS and ZnTPP. Due to the relative stability of the radical anions and cations of ZnTPP electron transfer can be monitored more easily.

EXPERIMENTAL

Nonstoichiometric CdS clusters were prepared in CH_3CN and 2-propanol using the method of "arrested precipitation"²⁰. Details are given elsewhere¹¹. Colloidal suspensions of $2 \times 10^{-4} \text{ M}$ CdS with $8 \times 10^{-4} \text{ M}$ Cd^{2+} in CH_3CN are characterized by an emission maximum at 530-535 nm and a band gap energy (E_g), determined from plots of $\{\alpha(h\nu)\}^2$ vs $h\nu(\text{eV})$, equal to 3.05 eV. Another preparation of $1 \times 10^{-4} \text{ M}$ CdS with $9 \times 10^{-4} \text{ M}$ Cd^{2+} excess in CH_3CN was characterized by $(\lambda_{\text{em}})_{\text{max}} \approx 530\text{-}540 \text{ nm}$ and $E_g \approx 3.0 \text{ eV}$. Two different preparations of CdS clusters in 2-propanol, namely $2 \times 10^{-4} \text{ M}$ CdS with $5 \times 10^{-4} \text{ M}$ Cd^{2+} excess and $3 \times 10^{-4} \text{ M}$ CdS with $7 \times 10^{-4} \text{ M}$ Cd^{2+} excess, were characterized by $(\lambda_{\text{em}})_{\text{max}} = 535\text{-}540 \text{ nm}$, $E_g = 3.05 \text{ eV}$ and $(\lambda_{\text{em}})_{\text{max}} = 570\text{-}580 \text{ nm}$, $E_g \approx 2.9 \text{ eV}$, respectively. Zinc tetraphenylporphyrin was prepared from H_2TPP (chlorin free) and zinc acetate using methods from the literature²¹. Cadmium tetraphenylporphyrin

was prepared as a complex in solution in the presence of excess Cd^{2+} and was characterized spectroscopically.

RESULTS AND DISCUSSION

The recombination luminescence of CdS in CH_3CN and in 2-propanol, excited at 364 ± 1 nm, is quenched considerably by ZnTPP and to a less extent by CdTPP. The quenching efficiency of a given electron acceptor (i.e. ZnTPP) increases with decreasing cluster size (larger E_g value and blue-shifted emission spectrum). The value of E_g is predicted to increase with decreasing size of the cluster¹.

$$E_g = E_G + \frac{\hbar^2 \pi^2}{8R^2} (1/m_e^* + 1/m_h^*) - 1.8e^2/\epsilon R + \text{other terms} \quad (1)$$

where E_g is the band gap energy of a cluster with radius R , E_G is the band gap energy of the bulk semiconductor and m_e^* , m_h^* the effective masses of the electron and hole in the cluster. Clusters of CdS with similar particle size are quenched by ZnTPP and CdTPP to a different extent and to a less extent in the absence of O_2 . The recombination luminescence of CdS was monitored at the emission maximum of CdS clusters under consideration. The fluorescence of ZnTPP and CdTPP, excited at 546 nm, is not quenched by CdS clusters. Luminescence quenching of excited CdS clusters, $\text{CdS}(e^-/h^+)$, by ZnTPP and CdTPP cannot be described by the Stern-Volmer law at higher $[\text{ZnTPP}]$ and $[\text{CdTPP}]$ implying the participation of static rather than dynamic interactions. The initial slopes of Stern-Volmer plots (not shown), attributed to dynamic interactions at $[\text{Q}] \rightarrow 0$,

$$I_0/I_F = \{1 + (k_Q \tau) [\text{Q}]\} \exp [K[\text{Q}]] \quad (2)$$

are summarized in Table 1. ($k_Q \tau$ and K values).

TABLE 1 Stern-Volmer initial slopes of the recombination luminescence quenching of CdS clusters by metalloporphyrins. $k_Q \tau (\text{CdS } e^-/h^+)/M^{-1}$ and K/M^{-1} (in parentheses)

| SAMPLE | λ_{em} (nm) | E_g (eV) | ZnTPP | | CdTPP |
|--|-------------------------------|---------------|--|--|--|
| | | | Deaerated | Aerated | Aerated |
| $2 \times 10^{-4} \text{M CdS};$ $8 \times 10^{-4} \text{M Cd}^{2+}$ in CH_3CN . | 530-535 | 3.05 | 1.0×10^5 (1.0×10^5) | 1.5×10^5 (1.4×10^5) | 5.0×10^4 (5.2×10^4) |
| $1 \times 10^{-4} \text{M CdS};$ $9 \times 10^{-4} \text{M Cd}^{2+}$ in CH_3CN . | 535-540 | 3.0 | - | 1.3×10^5 (1.3×10^5) | - |
| $2 \times 10^{-4} \text{M CdS};$ $5 \times 10^{-4} \text{M Cd}^{2+}$ in 2-propanol. | 535-540 | 3.05 | - | 6.0×10^4 (6.0×10^4) | - |
| $3 \times 10^{-4} \text{M CdS};$ $7 \times 10^{-4} \text{M Cd}^{2+}$ in 2-propanol. | 570-580 | 2.9 | - | 2.0×10^4 (3.0×10^4) | - |

At higher quencher concentrations the exponential part (static interactions) of Eq(2) becomes more significant. Semilog plots of $(I_P)_{\text{cds}}^0 / (I_P)_{\text{cds}}^Q$ vs $[Q]$, shown in Fig. 1 lead to straight lines, with one notable exception. The recombination luminescence quenching of $\text{CdS}(e^-/h^+)$ is attributed to electron transfer of e^-_{CB} to the appropriate electron acceptor. The criterion for such electron transfer process is:

$$\Delta G_{\text{el.tr}} = E^0(\text{CdS}^+/\text{CdS}(e^-/h^+)) - E^0(Q/Q^-) - e^2/\epsilon R < 0 \quad (3)$$

where R is the distance between donor and acceptor in the precursor ion-pair. The lack of quenching of the fluorescence emission of $\text{ZnTPP}(\text{CdTPP})$ by CdS implies $E^0(\text{CdS}/\text{CdS}^-) < E^0(\text{ZnTPP}^+/\text{ZnTPP}^*)$, i.e. the redox potential of CdS is more negative than the redox potential of ZnTPP^* . Similarly, recombination luminescence quenching of $\text{CdS}(e^-/h^+)$ by ZnTPP and CdTPP implies $E^0(\text{CdS}^+/\text{CdS}(e^-/h^+)) < E^0(\text{ZnTPP}/\text{ZnTPP}^*)$.

Electron transfer from the conduction band of CdS to ZnTPP and CdTPP is accompanied by drastic changes in both the absorption and emission spectra of ZnTPP and CdTPP . The characteristic absorption bands of the metalloporphyrin (Soret and Q-bands) nearly disappear and are replaced by new weak bands at 450-500 nm, 640 nm and in the UV region. Typical absorption spectra of ZnTPP , irradiated at 365 nm in the presence of CdS are shown in Fig. 2. In the presence of O_2 the photodamage brought about on ZnTPP in the presence of excited CdS is enhanced. The lack of well defined isosbestic points is indicative of the existence of different photochemical mechanisms in deaerated and air saturated systems. It should be pointed out that ZnTPP irradiated under similar conditions in the absence of CdS clusters remained totally unchanged.

The luminescence spectra of the photoproducts of ZnTPP formed in the presence of CdS are totally different from those of ZnTPP . They are strongly dependent upon the excitation wavelength. Emission spectra of ZnTPP-CdS samples in CH_3CN ($\lambda_{\text{exc}}=546$) consist of a strong broad emission band at about 600 nm (slightly blue-shifted from 603 nm) and an extremely weak and broad band at about 650 to 655 nm (Fig. 3). The latter emission band becomes very strong, very broad and slightly red-shifted under excitation at 365 nm. Under the same excitation conditions the emission band at about 600 nm becomes very weak (approximately 1/5 of that at 655 nm following 3 hours irradiation at 365 nm). It is apparent that more than one photoproduct are produced. Although the primary reduction product is expected to be ZnTPP^- or ZnTPPH^- with a Soret band at about 455 nm [13], the final reduction

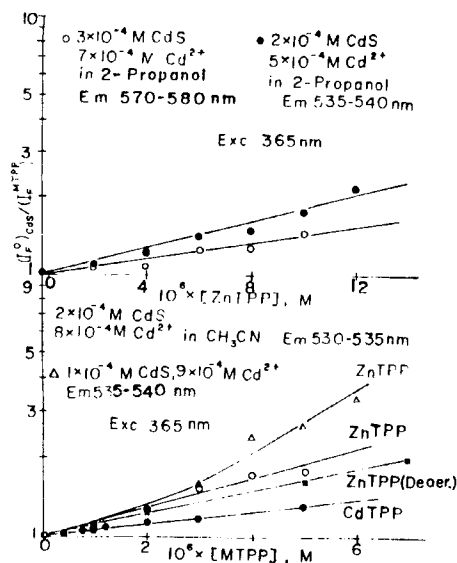


Fig. 1 Semilog plots of recombination luminescence quenching of CdS clusters by metalloporphyrins

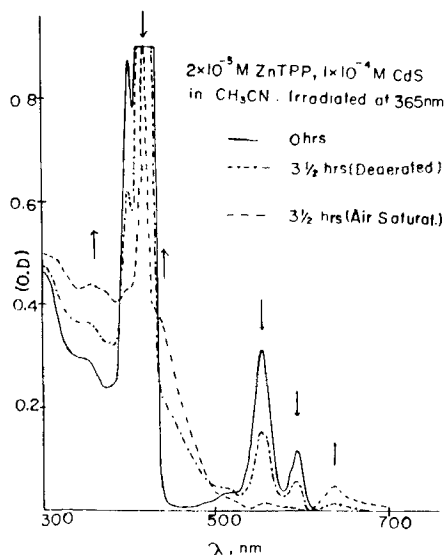


Fig. 2 Absorption spectra of non-irradiated and UV-irradiated CdS-ZnTPP mixtures.

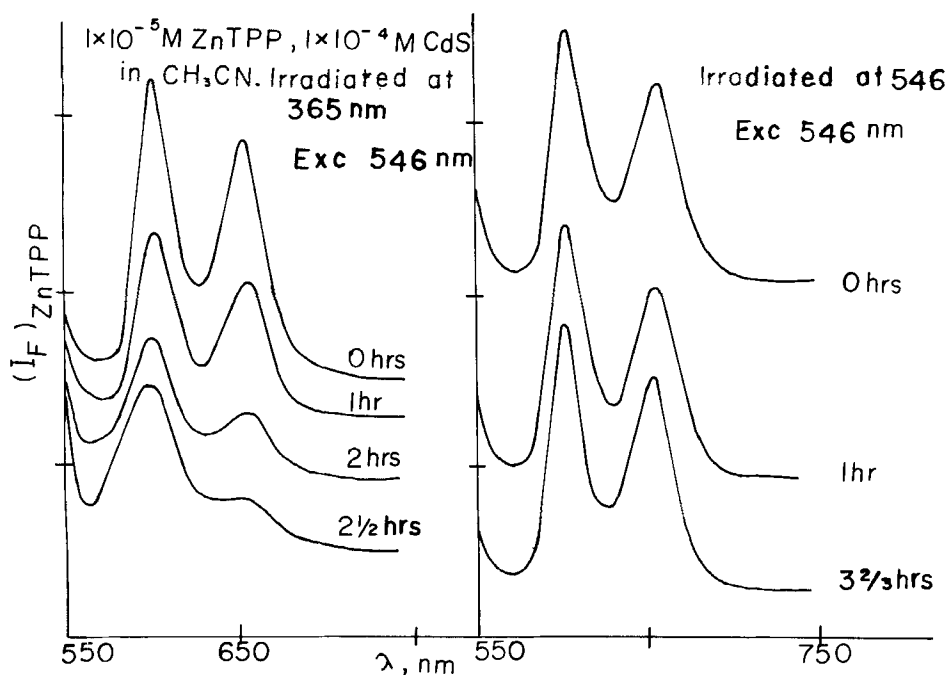


Fig. 3 Luminescence spectra of ZnTPP irradiated at different time intervals at 365 and 546 nm in the presence of CdS clusters.

product is more likely to be tetraphenylphlorin with a weak absorption band at 600-640 nm, weak UV absorption and emission at 655-660 nm. In addition, the role of O_2^- , formed via an electron-transfer process from $CdS(e^-/h^+)$ to O_2 , is not clear at this time. The intensity of recombination luminescence is about 20% lower than that of deaerated systems. Whether O_2 mediates electron transfer from $CdS(e^-/h^+)$ to ZnTPP, leads to oxidation products, or both remains to be determined.

Studies are underway leading to quantitative photodamage of ZnTPP and CdTPP in deaerated and air saturated systems in the presence of CdS clusters. A larger scale production of photoproducts is required, at short irradiation times, for a successful NMR product identification. In addition, several other metalloporphyrins (different redox potentials) are being used to probe the size-dependence of interfacial electron transfer.

REFERENCES

1. L.E. Brus, J. Chem. Phys. **79**, 556, (1983); **80**, 4403 (1984).
2. H. Weller, A. Fojtik and A. Henglein, Chem. Phys. Lett. **117**, 485, (1985).
3. A. Fojtik, H. Weller and A. Henglein, Chem. Phys. Lett. **120**, 552 (1985).
4. N. Chestnoy, T.D. Harris, R.Hull and L.E. Brus, J. Phys. Chem. **90**, 3393 (1986).
5. H. Spanhel, H. Weller, A. Fojtik and A. Henglein, Ber. Bunsenges. Phys. Chem. **91**, 88 (1987).
6. L.E. Brus, IEEE J. Quant. Electronics, QE-22, 1909 (1986).
7. L.E. Brus, J. Phys. Chem. **90**, 2555 (1986).
8. A.I. Ekimov and A.A. Onuschenko, JETP Let. (Engl. Transl.) **40** 1136 (1984).
9. P.V. Kamat, N.M. Dimitrijevic and R.W. Fessenden, J. Phys. Chem. **91**, 396 (1987).
10. J. Chrysochoos and Y.F. Lee, XII IUPAC Symp. on Photochemistry, 229 (1988).
11. Y.F. Lee, M. Olshavsky and J. Chrysochoos, J. Less-Comm. Metals, **148**, 259 (1989).
12. J. Chrysochoos, Spectrum **2(3)**, 16 (1989).
13. G.L. Closs and L.E. Closs, J. Am. Chem. Soc. **85**, 818 (1963).
14. D.W. Clack and N.S. Hush, J. Am. Chem. Soc., **87**, 4238 (1965).
15. G. Peychal-Heiling and G.S. Wilson, Anal. Chem. **43**, 550 (1971).
16. D. Mazerall, in The Porphyrins (Ed. D. Dolphin) v **5**, 29 (1978).
17. R.H. Felton, Ibid v **5**, 53 (1978).
18. W. Potter, R.N. Young, G. Levin, J. Am. Chem. Soc., **102**, 2471 (1980).
19. A. Harriman, G. Porter and N. Searle, J. Chem. Soc., Faraday Trans. 2, **75**, 1515 (1979).
20. R. Rossetti, R. Hull, J.M. Gibson and L.E. Brus, J. Chem. Phys., **82**, 552 (1985), **83**, 1406 (1985).
21. A.D. Adler, F.R. Longo, F. Kampas and J. Kim, J. Inorg. and Nucl. Chem. **32**, 2443 (1970).